

Notice of References Cited

Application/Control No.

10/532,782

Applicant(s)/Patent Under
Reexamination
KUMAKURA ET AL.

Examiner

Jonathan C. Langman

Art Unit

1775

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U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	A	US-5,741,724	04-1998	Ramdani et al.	438/46
*	B	US-6,362,515	03-2002	Hayakawa, Toshiro	257/639
*	C	US-6,744,076	06-2004	Fukuyama et al.	257/103
	D	US-			
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	O					
	P					
	Q					
	R					
	S					
	T					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Cho et al., "Effects of N+-implanted sapphire (0001) substrate on GaN epilayer". Journal of Crystal Growth, Volume 236, Issue 4, March 2002, Pages 538-544
	V	Liu et al., "Substrates for gallium nitride epitaxy". Materials Science and Engineering: R: Reports, Volume 37, Issue 3, 30 April 2002, Pages 61-127.
	W	
	X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.